

**Pyroelectric Infrared  
Radial Sensor**



<http://en.nyenba.com>

**TYPE: AS612**

**NANYANG SENBA OPTICAL AND ELECTRONIC CO., LTD.**

Digital Smart Pyroelectric Detector AS612

AS612 is a newest smart digital motion detector with a small window size.



It offers a complete motion detector solution, with all electronic circuitry built into the detector housing. Only a power supply and power-switching components need to be added to make the entire motion switch.

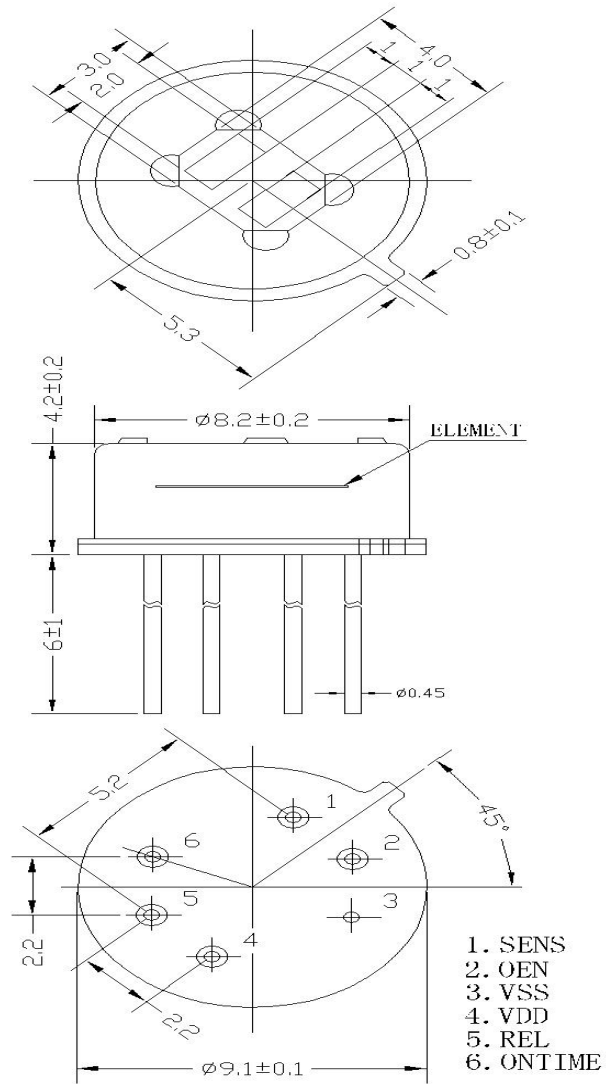
AS612 includes the setting for time, sensitivity and ambient light level.

## ■ Features and Benefits

- Digital signal processing (DSP)
- Power adjustable, save more energy
- Two-way differential high impedance sensor input
- Built-in filter, screen the interference by other frequency
- Excellent power supply rejection, Insensitive to RF interference
- Schmidt REL output
- Low voltage, low power consumption, instantaneous settling after power up

## ■ Applications

- Toys
- Digital photo frame
- TV, Refrigerator, Air-conditioner
- USB Alarms
- PIR motion detection
- Intruder detection
- Occupancy detection
- Motion sensor lights
- Computer monitor
- Security system
- Automatic control
- Corridor
- Stairs Lights etc.

**Dimension**


PIR Dimension

**■ Technical Data**
**1. Maximum Ratings**

Characteristic s	Symbo l	Min. Value	Max. Value	Unit	Remarks
Supply Voltage	VDD	-0.3	3.6	V	
Working Temperature	TST	-20	85	°C	
Max.current for pin	Into	-100	100	mA	
Storage Temperature	TST	-40	125	°C	

**2. Working Conditions (T=25°C, Vdd=3V, Except other requirements)**

Characteristics	Sym bol	Min.	Typ e	Max.	Unit	Remarks
Supply Voltage	V <sub>DD</sub>	2.7	3	3.3	V	IR=0.5mA
Working Current	I <sub>DD</sub>	12	15	20	μA	
Sensitivity	V <sub>SEN</sub> s	120		530	μV	
<b>Output REL</b>						
Output Low Current	I <sub>OL</sub>	10			mA	V <sub>OL</sub> <1V
Output High Current	I <sub>OH</sub>			-10	mA	V <sub>OL</sub> >(V <sub>DD</sub> .1V)
Lock time	T <sub>OL</sub>		2.3		s	
On-time	T <sub>OH</sub>	2.3		4793	s	
<b>SENS/ONTIME</b>						
Input voltage		0		V <sub>DD</sub>	V	0V to ¼ V <sub>DD</sub>
Input Bias Current		-1		1	μA	
<b>OEN</b>						

Input Low Voltage	$V_{IL}$			0.2	Vdd	
Input High Voltage	$V_{IH}$	0.4			Vdd	
Input Current	$I_i$	-1		1	$\mu A$	$V_{SS} < V_{IN} < V_{DD}$
<b>Oscillator &amp; Filter</b>						
Low pass filter cut-off frequency				7	Hz	
High pass filter cut-off frequency				0.44	Hz	
Oscillator frequency on Chip	$F_{CLK}$			64	kHz	
Interior Block Diagram						

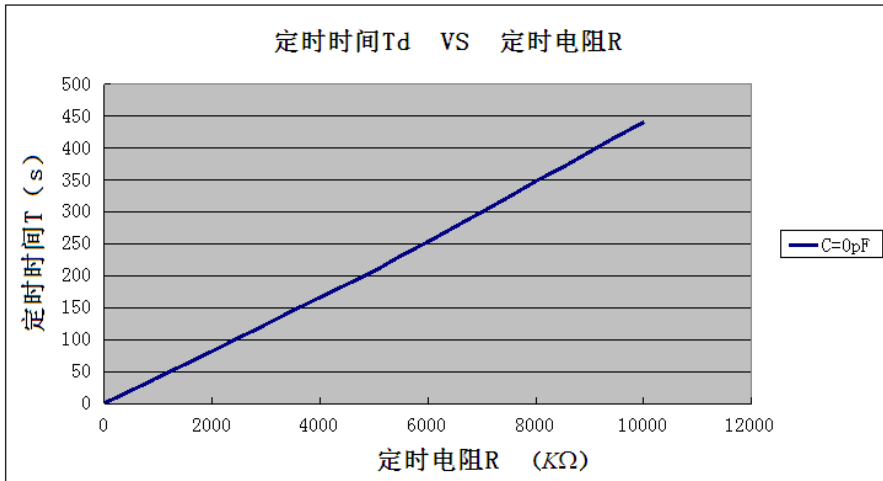
## ■ On-time Setting

### 1. Analog setting style for on-time

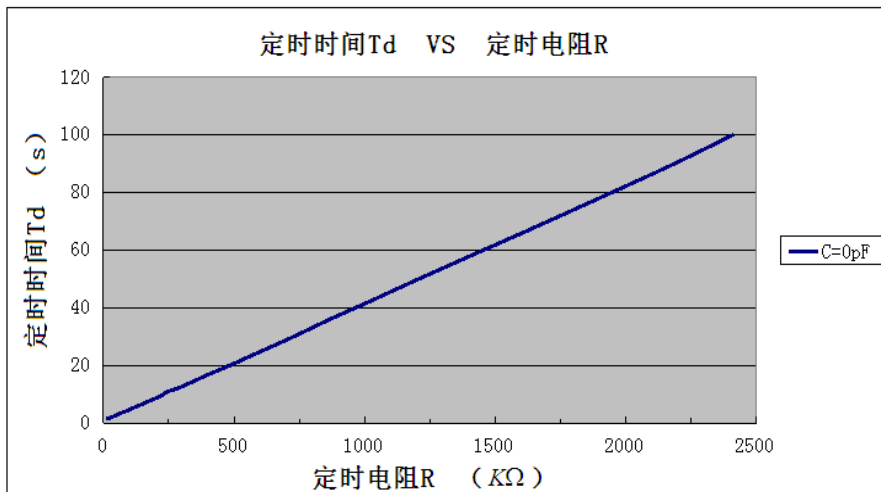
Td: On-time time

R: On-time Resistor

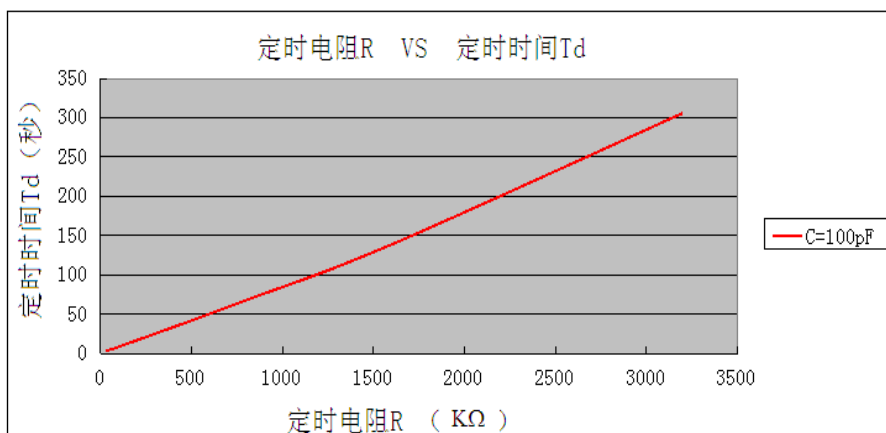
C: On-time Capacitor



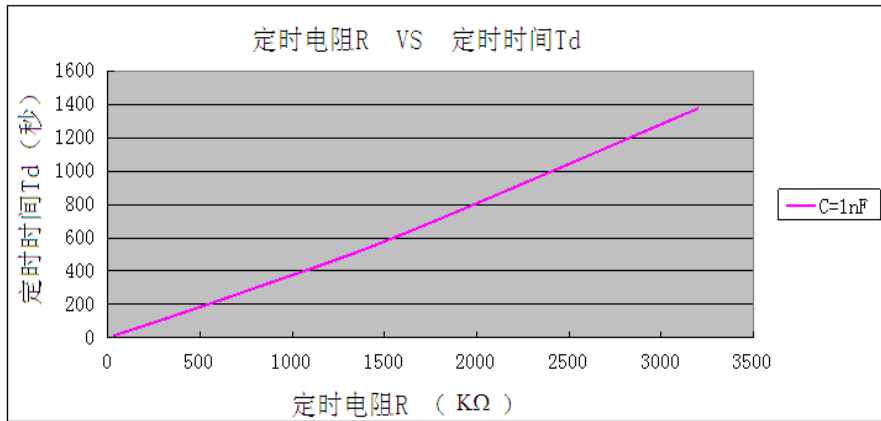
\*  $C=0pF$



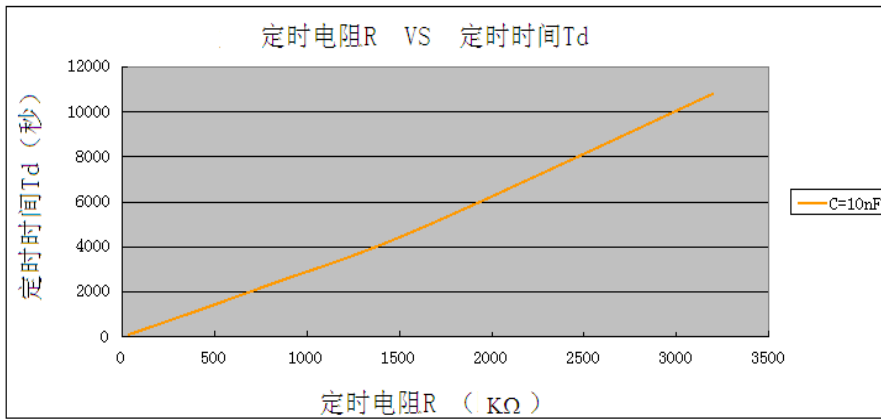
\*  $C=0pF$



\*  $C=100pF$



\* C=1nF



\* C=10nF

**2. Digital setting style for on-time**

No	On-time Voltage (VDD)	On-time center Voltage (VDD)	Pull-down-Resistor ( $\Omega$ ) (Pull-up=1M)	Time (Td) (sec)
0	0~1/32	1/64	0K	1.8
1	1/32~2/32	3/64	51k	3.6
2	2/32~3/32	5/64	91k	5.4
3	3/32~4/32	7/64	120k	7.2
4	4/32~5/32	9/64	180k	14.4
5	5/32~6/32	11/64	220k	29
6	6/32~7/32	13/64	270k	43
7	7/32~8/32	15/64	330k	58
8	8/32~9/32	17/64	360k	115
9	9/32~10/32	19/64	430k	230
10	10/32~11/32	21/64	510k	346
11	11/32~12/32	23/64	560k	461
12	12/32~13/32	25/64	680k	922
13	13/32~14/32	27/64	750k	1843
14	14/32~15/32	29/64	910k	2765
15	15/32~16/32	31/64	1M	3686

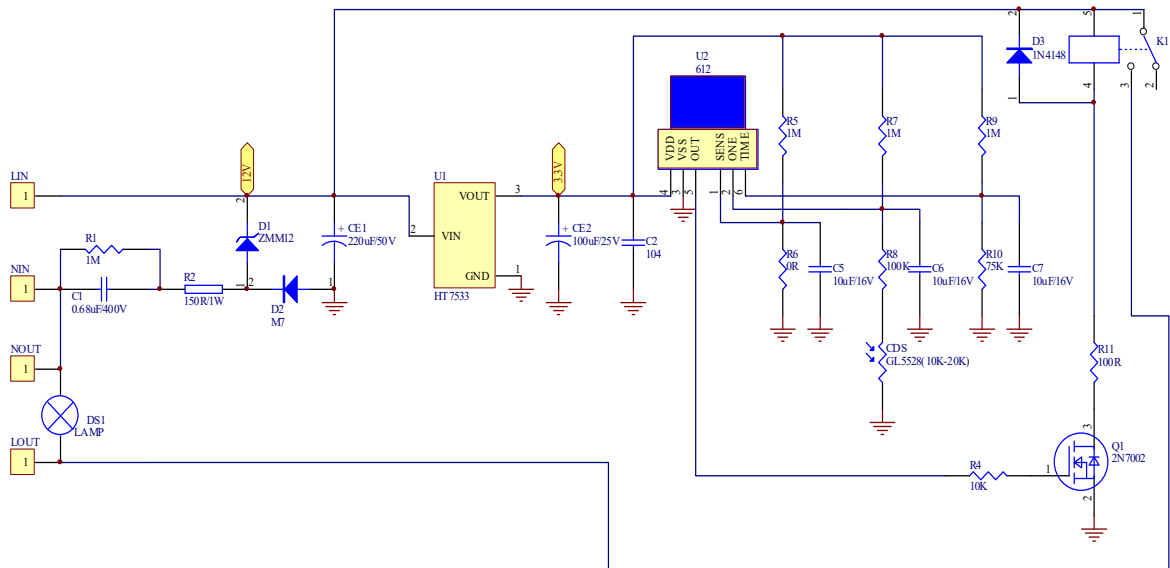


**■ Sensitivity Setting**

	$V_{SENS}$			$V_{SENS}$	
	Voltage Range ( $V_{DD}$ )	Center Voltage ( $V_{DD}$ )		Voltage Range ( $V_{DD}$ )	Center Voltage ( $V_{DD}$ )
0	0~1/64	1/128	1 6	16/64~17/64	33/128
1	1/64~2/64	3/128	1 7	17/64~18/64	35/128
2	2/64~3/64	5/128	1 8	18/64~19/64	37/128
3	3/64~4/64	7/128	1 9	19/64~20/64	39/128
4	4/64~5/64	9/128	2 0	20/64~21/64	41/128
5	5/64~6/64	11/128	2 1	21/64~22/64	43/128
6	6/64~7/64	13/128	2 2	22/64~23/64	45/128
7	7/64~8/64	15/128	2 3	23/64~24/64	47/128
8	8/64~9/64	17/128	2 4	24/64~25/64	49/128
9	9/64~10/64	19/128	2 5	25/64~26/64	51/128
10	10/64~11/64	21/128	2 6	26/64~27/64	53/128
11	11/64~12/64	23/128	2 7	27/64~28/64	55/128
12	12/64~13/64	25/128	2 8	28/64~29/64	57/128

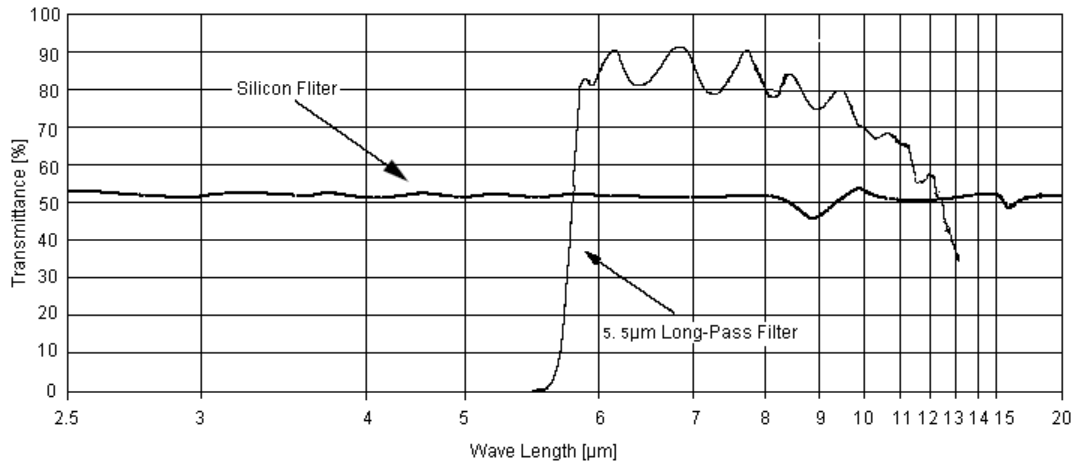
1	13/64~14/64	27/128	2	29/64~30/64	59/128
3			9		
1	14/64~15/64	29/128	3	30/64~31/64	61/128
4			0		
1	15/64~16/64	31/128	3	31/64~32/64	63/128
5			1		

■ Typical Application



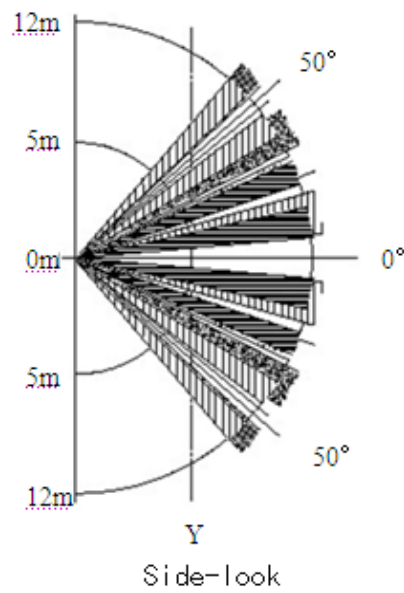
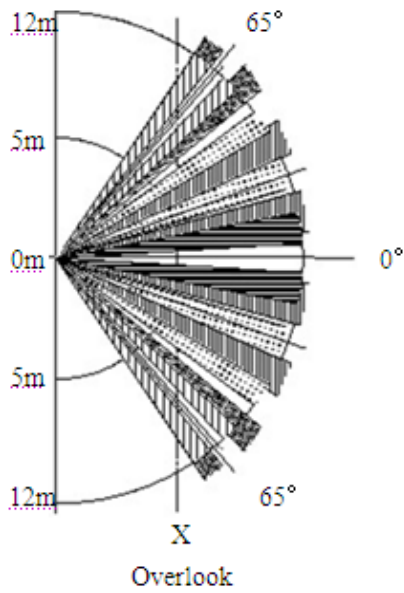
Notes: The circuit design for PIR Sensor AS612 .

## ■ Spectral Response of Window Materials

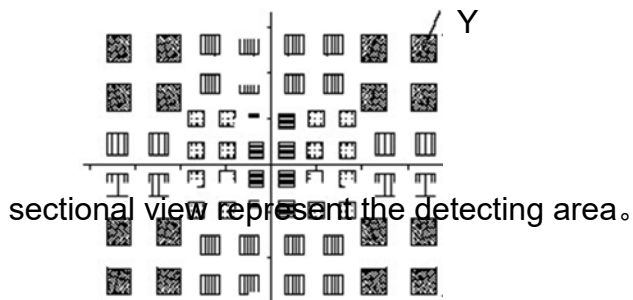


**Notes: The average transitivity curve for silicon filter with 5.5μm pass IR filter**

**Detection View**



X-Y sectional view



detecting zone

Notes: 1.X-Y

sectional view represent the detecting area.

X

2.Objects with temperature difference can be

Detected in the

vertical level.

12m 9 6 3 3 6 9 12m



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